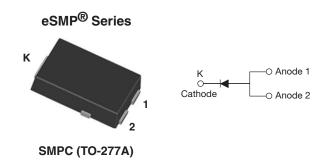
RoHS

COMPLIANT

HALOGEN

Vishay Semiconductors

# Hyperfast Rectifier, 4 A FRED Pt®



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### LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS					
I <sub>F(AV)</sub>	4 A				
V <sub>R</sub>	100 V				
V <sub>F</sub> at I <sub>F</sub>	0.73 V				
t <sub>rr (typ.)</sub>	27 ns				
T <sub>J</sub> max.	175 °C				
Package	SMPC (TO-277A)				
Circuit configuration	Single				

#### **FEATURES**

- Hyperfast recovery time, reduced Q<sub>rr</sub>, and soft recovery
- 175 °C maximum operating junction temperature
- Specified for output and snubber operation
- Low forward voltage drop
- Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified, meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### **DESCRIPTION / APPLICATIONS**

State of the art hyperfast recovery rectifiers specifically designed with optimized performance of forward voltage drop and hyperfast recovery time.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness, and reliability characteristics.

These devices are intended for use in snubber, boost, lighting, piezo-injection, as high frequency rectifiers and freewheeling diodes.

The extremely optimized stored charge and low recovery current minimize the switching losses and reduce power dissipation in the switching element.

### **MECHANICAL DATA**

Case: SMPC (TO-277A)

Molding compound meets UL 94 V-0 flammability rating Halogen-free, RoHS compliant

**Terminals:** matte tin plated leads, solderable per J-STD-002

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Peak repetitive reverse voltage	V <sub>RRM</sub>		100	V			
Average rectified forward current	I <sub>F(AV)</sub>	T <sub>Sp</sub> = 165 °C	4	A			
Non-repetitive peak surge current	I <sub>FSM</sub>	T <sub>J</sub> = 25 °C	130				
Operating junction and storage temperatures	T <sub>J</sub> , T <sub>Stg</sub>		-55 to +175	°C			

<b>ELECTRICAL SPECIFICATIONS</b> ( $T_J = 25$ °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	$V_{BR}$ , $V_{R}$	I <sub>R</sub> = 100 μA	100	-	-		
Forward voltage	V	$I_F = 4 A$	-	0.86	0.93	V	
	V <sub>F</sub>	I <sub>F</sub> = 4 A, T <sub>J</sub> = 125 °C	-	0.73	0.79		
Reverse leakage current		$V_R = V_R$ rated	-	-	2		
	IR	$T_J = 125 \text{ °C}, V_R = V_R \text{ rated}$	-	1	10	μA	
Junction capacitance	CT	V <sub>R</sub> = 100 V	-	24	-	pF	

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<b>DYNAMIC RECOVERY CHARACTERISTICS</b> ( $T_J = 25$ °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
		$I_F = 1 \text{ A}, \text{ d}I_F/\text{d}t = 5$	50 A/µs, V <sub>R</sub> = 30 V	-	27	-	
Poverse receiver time		$I_F = 0.5 \text{ A}, I_R = 1 \text{ A}, I_{rr} = 0.25 \text{ A}$		-	-	25	
Reverse recovery time	t <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	20	-	A
		T <sub>J</sub> = 125 °C	I <sub>F</sub> = 4 A dI <sub>F</sub> /dt = 200 A/µs V <sub>B</sub> = 160 V	-	31	-	
Poole recovery ourrent	I <sub>RRM</sub>	T <sub>J</sub> = 25 °C		-	2.2	-	
Peak recovery current		T <sub>J</sub> = 125 °C		-	4.4	-	A
	0	T <sub>J</sub> = 25 °C		-	22	-	nC
Reverse recovery charge	Q <sub>rr</sub>	T <sub>J</sub> = 125 °C		-	70	-	nC

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-55	-	175	°C	
Thermal resistance, junction to mount	R <sub>thJM</sub>		-	2.2	3	°C/W	
Thermal resistance, junction to ambient	R <sub>thJA</sub>		-	85	-	0/11	
Approximate weight				0.1		g	
Approximate weight				0.0035		oz.	
Marking device		Case style SMPC (TO-277A)	JEH1				



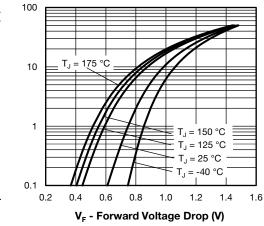


Fig. 1 - Typical Forward Voltage Drop Characteristics

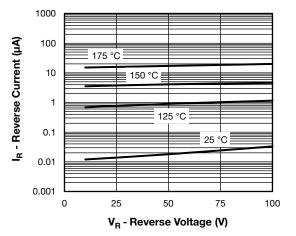
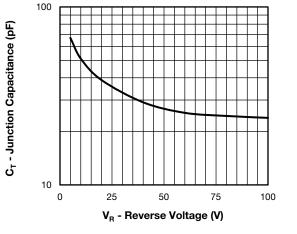


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage



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Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

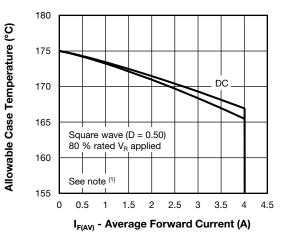


Fig. 4 - Maximum Allowable Case Temperature vs. Average Forward Current

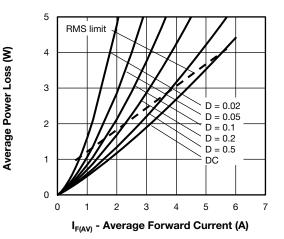


Fig. 5 - Forward Power Loss Characteristics

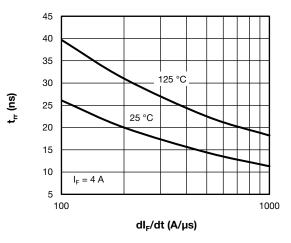


Fig. 6 - Typical Reverse Recovery Time vs. dI<sub>F</sub>/dt

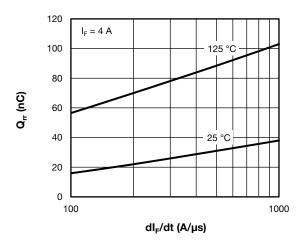


Fig. 7 - Typical Stored Charge vs. dl<sub>F</sub>/dt

#### Note

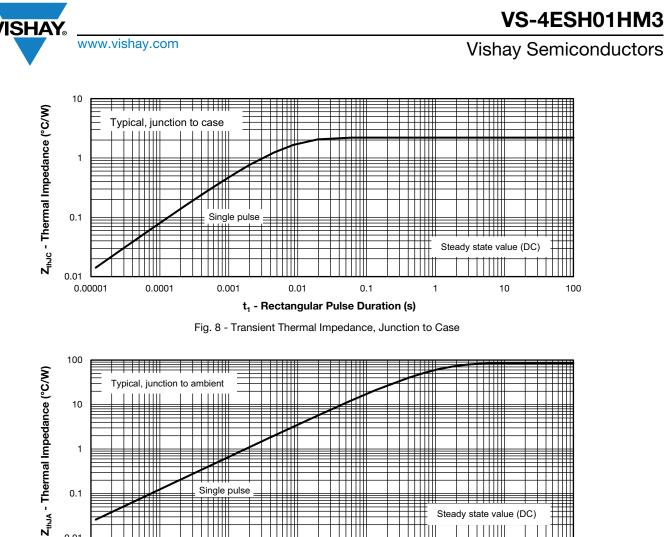
<sup>(1)</sup> Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ;

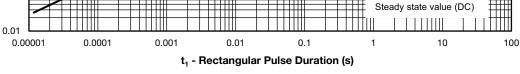
 $\begin{array}{l} \mathsf{Pd} = \mathsf{forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \ \mathsf{x} \ \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{5}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \ \mathsf{x} \ \mathsf{I}_{\mathsf{R}} \ (1 - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$ 

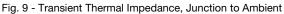
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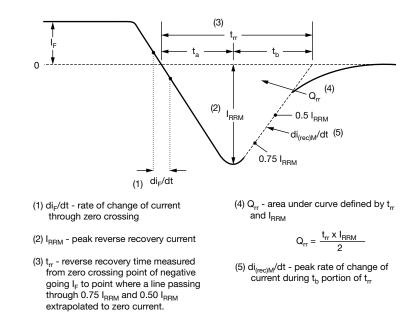
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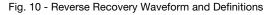
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### **ORDERING INFORMATION TABLE**

Device code	vs-	4	Е	s	н	01	н	М3	
		2	3	4	5	6	7	8	
	1	- Visl	nay Sen	nicondu	ctors pro	oduct			
	2	Cur	rent rati	ng (4 = 4	4 A)				
	3.	- Circ	uit conf	iguratio	n:				
		E =	single c	liode					
	4	- S=	SMPC	package	Э				
	5	- Pro	cess typ	be,					
		H =	hyperfa	st recov	/ery				
	<b>6</b>	- Volt	age coo	de (01 =	100 V)				
	7.	. н=	AEC-Q	101 qua	alified				
	8	- M3	= halog	en-free,	RoHS-0	complia	nt, and	termina	tions le

ORDERING INFORMATION (Example)								
PREFERRED P/N	QUANTITY PER REEL	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION					
VS-4ESH01HM3/86A	1500	1500	7" diameter plastic tape and reel					
VS-4ESH01HM3/87A	6500	6500	13" diameter plastic tape and reel					

LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95570				
Part marking information	www.vishay.com/doc?95565				
Packaging information	www.vishay.com/doc?88869				
SPICE model	www.vishay.com/doc?96073				

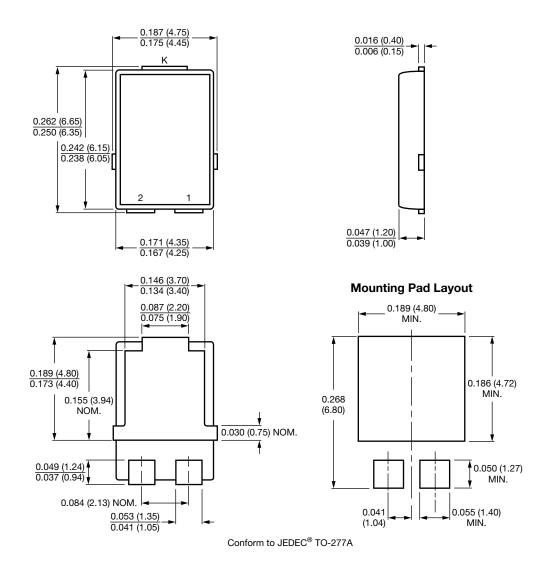
# **Outline Dimensions**





SMPC (TO-277A)

#### **DIMENSIONS** in inches (millimeters)





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